

2STW1695

High power PNP epitaxial planar bipolar transistor

Features

- High breakdown voltage V_{CEO} = -140 V
- Complementary to 2STW4468
- Typical f_t = 20 MHz
- Fully characterized at 125 °C

Applications

■ Audio power amplifier

Description

The device is a PNP transistor manufactured using new BiT-LA (Bipolar transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour. Recommended for 70 W to 100 W high fidelity audio frequency amplifier output stage.

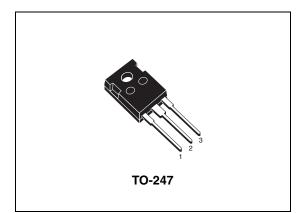


Figure 1. Internal schematic diagram

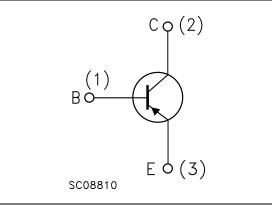


Table 1.	Device	summary
	DCVICC	Summury

Order code	Marking	Package	Packaging
2STW1695	2STW1695	TO-247	Tube

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage ($I_E = 0$)	-140	V
V _{CEO}	Collector-emitter voltage $(I_B = 0)$	-140	V
V _{EBO}	Emitter-base voltage ($I_{C} = 0$)	-6	V
Ι _C	Collector current	-10	A
I _{CM}	Collector peak current ($t_P < 5 \text{ ms}$)	-20	A
P _{tot}	Total dissipation at $T_c = 25 \ ^{\circ}C$	100	W
T _{stg}	Storage temperature	-65 to 150	°C
ТJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter		Value	Unit
R _{thj-case}	Thermal resistance junction-case	max	1.25	°C/W

2 Electrical characteristics

(T_{case} = 25 °C; unless otherwise specified)

Table 4. Electrical characte	eristics
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Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = -140 V			-0.1	μA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = -6 V			-0.1	μA
V _{(BR)CEO}	Collector-emitter breakdown voltage (I _B = 0)	I _C = -50 mA	-140			v
V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	I _C = -100 μA	-140			v
	Emitter-base breakdown voltage (I _C = 0)	I _E = -1 mA	-6			v
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_{C} = -5 A$ $I_{B} = -500 mA$ $I_{C} = -7 A$ $I_{B} = -700 mA$			-0.5 -0.7	V V
V _{BE} ⁽¹⁾	Base-emitter voltage	V _{CE} = -5 V I _C = -5 A			-1.3	V
h _{FE}	DC current gain	$I_{C} = -3 A$ $V_{CE} = -4 V$ $I_{C} = -5 A$ $V_{CE} = -4 V$	70 50		140	
f _T	Transition frequency	I _C = -0.5 A V _{CE} = -12 V		20		MHz
C _{CBO}	Collector-base capacitance (I _E = 0)	V _{CB} = -10 V f = 1 MHz		225		pF
	Resistive load					
t _{on}	Turn-on time	I _C = -5 A V _{CC} = -60 V		0.24		μs
t _{stg}	Storage time	I _{B1} = -I _{B2} = -0.5 A		1.2		μs
t _f	Fall time			0.24		μs

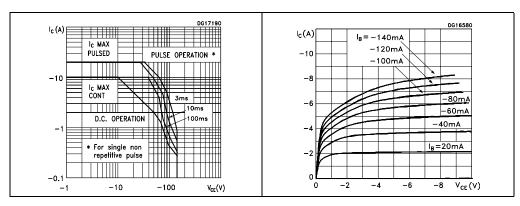
1. Pulsed: Pulse duration = 300 $\mu s,$ duty cycle \leq 1.5 %

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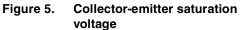
2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Output characteristics







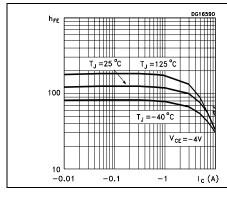


Figure 6. Base-emitter voltage

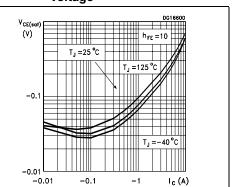
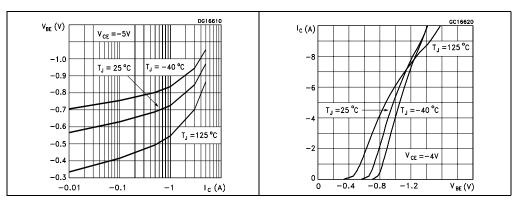


Figure 7. Base-emitter voltage



2.2 Test circuit

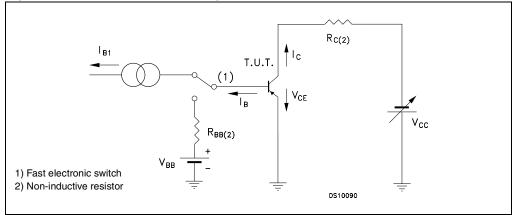


Figure 8. Resistive load switching test circuit



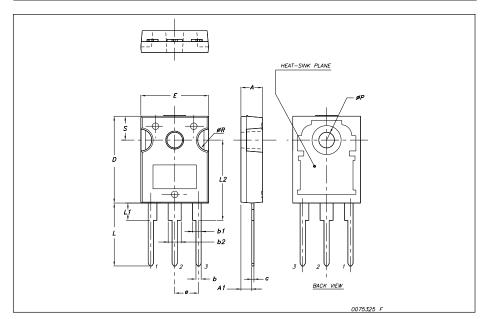
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



	TO-247 Mechanical data		
Dim.		mm.	
Dini.	Min.	Тур	Max.
Α	4.85		5.15
A1	2.20		2.60
b	1.0		1.40
b1	2.0		2.40
b2	3.0		3.40
С	0.40		0.80
D	19.85		20.15
Е	15.45		15.75
е		5.45	
L	14.20		14.80
L1	3.70		4.30
L2		18.50	
øР	3.55		3.65
øR	4.50		5.50
S		5.50	







4 Revision history

Date	Revision	Changes
23-Oct-2006	1	Initial release
23-Sep-2007	2	Added figures 2, 3, 4, 5, 6, 7.
20-Feb-2007	3	Document status promoted from preliminary data to datasheet.
06-Oct-2008	4	Content reworked to improve readability, no technical changes.

Table 5.Document revision history

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